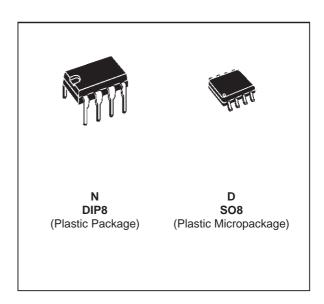




PRECISION SINGLE OPERATIONAL AMPLIFIER

- INPUT OFFSET VOLTAGE : 3mV max. OVER TEMPERATURE
- FREQUENCY COMPENSATION WITH A SINGLE 30pF CAPACITOR (C1)
- OPERATION FROM ±5V to ±15V
- LOW POWER CONSUMPTION: 50mW AT±15V
- CONTINUOUS SHORT-CIRCUIT PROTECTION
- OPERATION AS A COMPARATOR WITH DIFFERENTIAL INPUTS AS HIGH AS ±30V
- NO LATCH-UP WHEN COMMON-MODE RANGE IS EXCEEDED
- SAME PIN CONFIGURATION AS THE LM101A



ORDER CODES

Part	Temperature	Package				
Number	Range	N	D			
UA748C	0°C, +70°C	•	•			
UA748I	-40°C, +105°C					
UA748M	-55°C, +125°C	•				
Example: UA748CN						

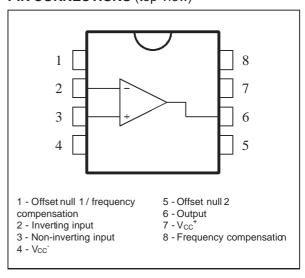
DESCRIPTION

The UA748 is a general purpose operational amplifier built on a single silicon chip. The resulting close match and tight thermal coupling gives low offsets and temperature drift as well as fast recovery from thermal transients.

- Short-circuit protection
- Offset voltage null capability
- Large common-mode and differential voltage ranges
- Low power consumption
- No latch-up

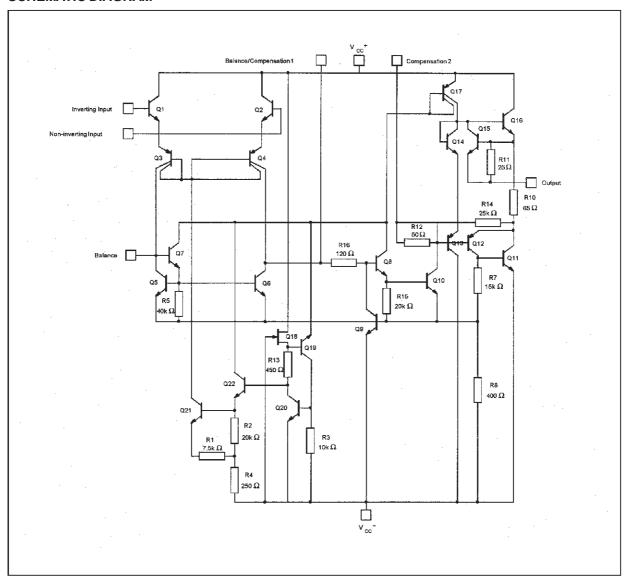
The unity-gain compensation specified makes the circuit stable for all feedback configurations, even with capacitive loads. However, it is possible to optimize compensation for best high frequency performance at any gain. The low power dissipation permits high voltage operation and simplifies packaging in full-temperature range systems.

PIN CONNECTIONS (top view)



December 1997 1/8

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

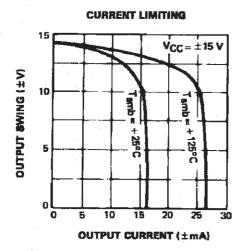
Symbol	Parameter	UA748M	UA748I	UA748C	Unit	
V _{cc}	Supply Voltage		V			
V _{id}	Differential Input Voltage		±30		V	
Vi	Input Voltage	±15				
P _{tot}	Power Dissipation	500				
	Output Short-circuit Duration	Infinite				
T _{oper}	Operating Free Air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C	
T _{stg}	Storage Temperature Range	-65 to +150	-65 to +150	-65 to +150	°C	

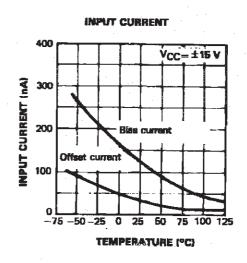
ELECTRICAL CHARACTERISTICS

 $\pm 5\text{V} \le \text{V}_{\text{CC}} \le \pm 20\text{V}, \text{C1} = 30\text{pF}, \text{T}_{\text{amb}} = +25^{\circ}\text{C}$ (unless otherwise specified)

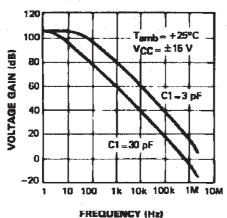
Symbol	Parameter		UA748I/M			UA748C		
	Farameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V _{io}	Input Offset Voltage ($R_S \le 10k\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		0.2	2 3		2	7.5 10	mV
l _{io}	Input Offset Current $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		25	75 10		70	250 300	nA
l _{ib}	Input Bias Current $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1.5	10 20		2	50 70	nA
A_{vd}	Large Signal Voltage Gain *	50 25	100		25 15	10		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	80 80	96		70 70	96		dB
I _{CC}	Supply Current, no load $ T_{amb} = +25^{\circ}C $ $ T_{min.} \leq T_{amb} \leq T_{max.} $		1.8	3		1.8	3	mA
V _{icm}	Input Common Mode Voltage Range ($V_{CC} = \pm 20V$) $T_{amb} = +25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	±15 ±15			±15 ±15			V
CMR	Common-mode Rejection Ratio (R _S \leq 10k Ω) $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	80 80	96		70 70	96		dB
los	Output Short-circuit Current (V _{CC} = ±15V)	10	30	50	10	30	50	mA
±V _{OPP}	$ \begin{array}{ll} \text{Output Voltage Swing } (V_{CC} = \pm 15 \text{V}) \\ \text{$T_{amb} = +25^{\circ}C$} & R_{L} = 10 \text{k}\Omega \\ \text{$R_{L} = 2 \text{k}\Omega$} \\ \text{$T_{min.} \leq T_{amb} \leq T_{max.}$} & R_{L} = 10 \text{k}\Omega \\ \text{$R_{L} = 2 \text{k}\Omega$} \end{array} $	12 10 12 10	14 13		12 10 12 10	14 13		V
SR	Slew Rate $(V_i = \pm 10V, R_L = 2k\Omega, C_L = 100pF, unity gain)$	0.25	0.5		0.25	0.5		V/µs
t _r	Rise Time $(V_i = \pm 20 \text{mV}, R_L = 2 \text{k}\Omega, C_L = 100 \text{pF}, \text{unity gain})$		0.3			0.3		μs
K _{OV}	Overshoot $(V_i = 20mV, R_L = 2k\Omega, CL = 100pF, unity gain)$		5			5		%
ZI	Input Impedance (V _{CC} = ±15V)	1.5	4		1.5	4		MΩ
Ro	Output Resistance (V _{CC} = ±15V)		75			75		Ω
GBP	Gain Bandwidth Product $(V_i = 10 \text{mV}, R_L = 2 \text{k}\Omega, C_L = 100 \text{pF}, f = 100 \text{kHz})$	0.5	1		0.5	1		MHz
THD	Total Harmonic Distortion (f = 1kHz, A_V = 20dB, R_L =2k Ω , V_O = 2 V_{PP} , C_L = 100pF)		0.015			0.015		%
DV _{io}			10 20	100 200		10 20	300 600	pA/°C
Dlio	$ \begin{array}{l} \text{Input Offset Voltage Drift} \\ T_{\text{min.}} \leq T_{\text{amb}} \leq T_{\text{max.}} \end{array} $		3	15		6	30	μV/°C



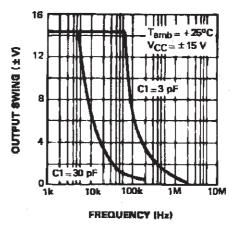




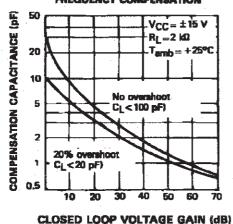




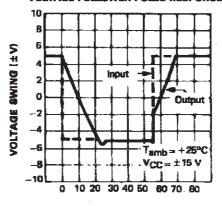




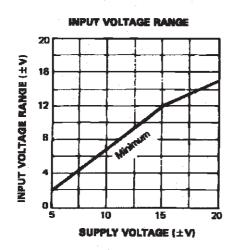


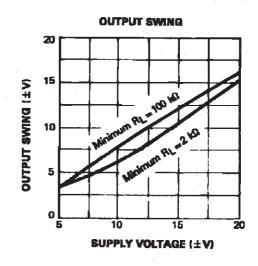


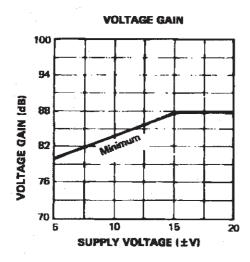


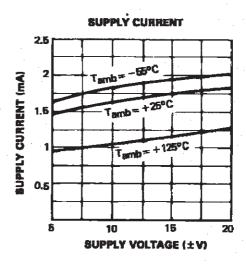


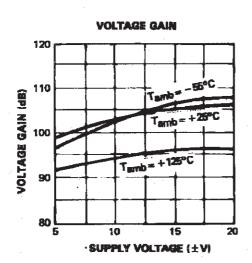
TIME (µb)

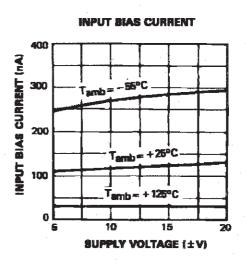






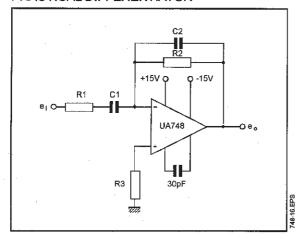




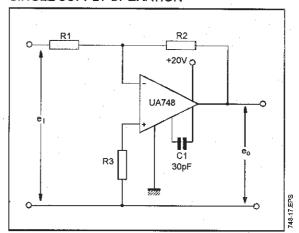


TYPICAL APPLICATIONS

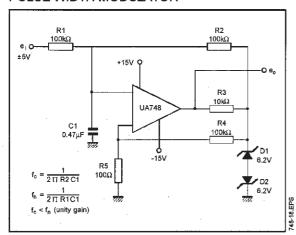
PRACTICAL DIFFERENTIATOR



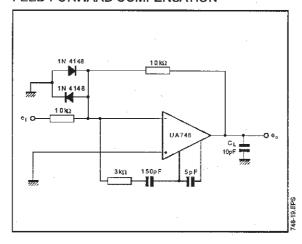
SINGLE SUPPLY OPERATION



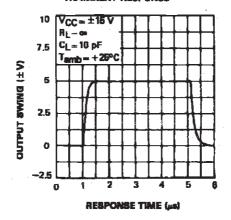
PULSE WIDTH MODULATOR



FEED-FORWARD COMPENSATION

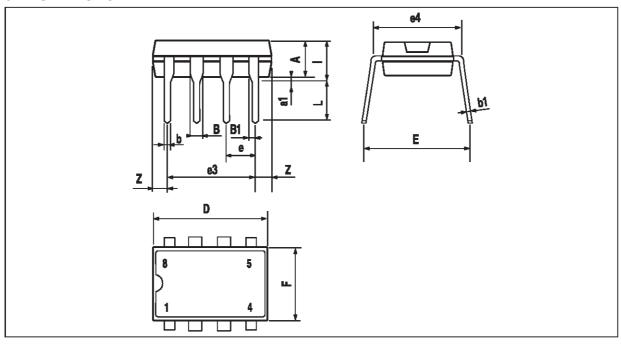


LARGE SIGNAL FEED-FORWARD TRANSIENT RESPONSE



PACKAGE MECHANICAL DATA

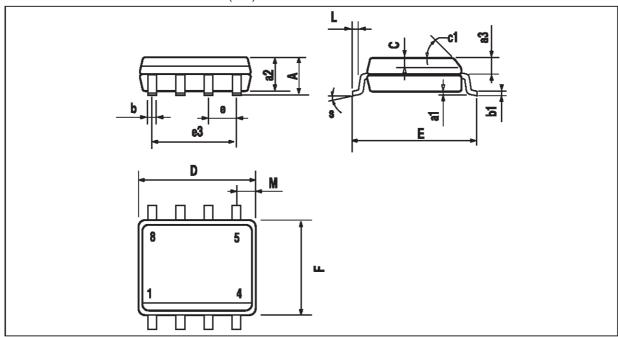
8 PINS - PLASTIC DIP



Dim.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
Е	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0260	
i			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52			0.060	

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1		•	45°	(typ.)	•	•	
D	4.8		5.0	0.189		0.197	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.150		0.157	
L	0.4		1.27	0.016		0.050	
M			0.6			0.024	
S	8° (max.)						

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